

2SD1306

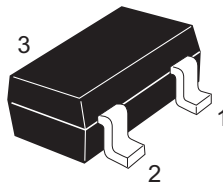
Silicon NPN Epitaxial

REJ03G0784-0200
(Previous ADE-208-1144)
Rev.2.00
Aug.10.2005

Application

Low frequency amplifier, Muting

Outline

RENESAS Package code: PLSP0003ZB-A
(Package name: MPAK)

1. Emitter
2. Base
3. Collector

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Collector to base voltage	V _{CB0}	30	V
Collector to emitter voltage	V _{CEO}	15	V
Emitter to base voltage	V _{EBO}	5	V
Collector current	I _C	0.7	A
Collector power dissipation	P _C	150	mW
Junction temperature	T _J	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

Electrical Characteristics

(Ta = 25°C)

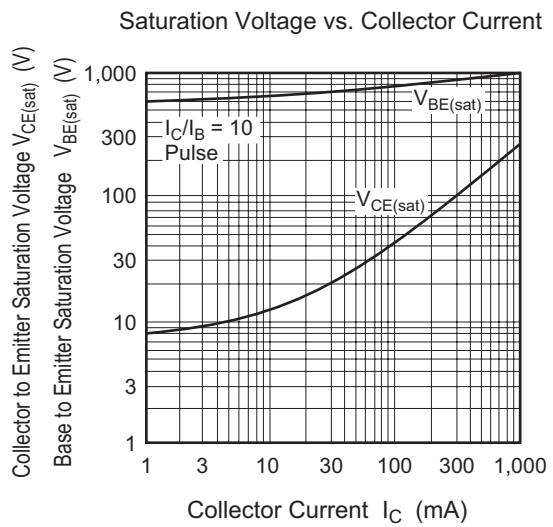
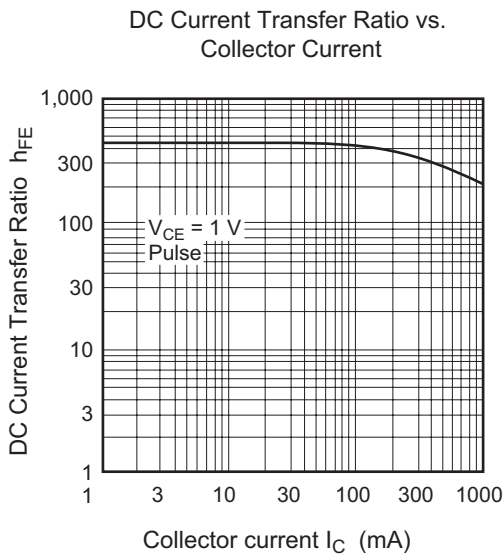
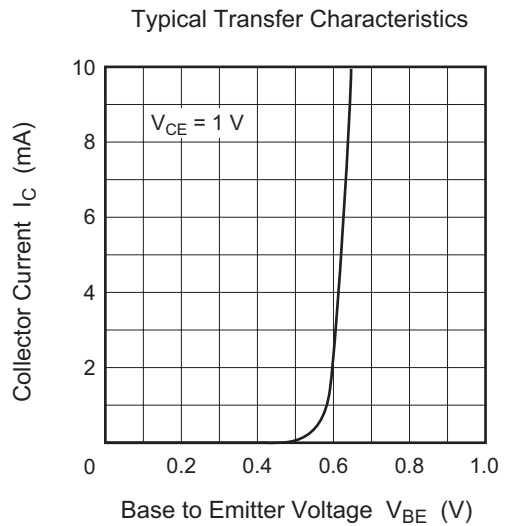
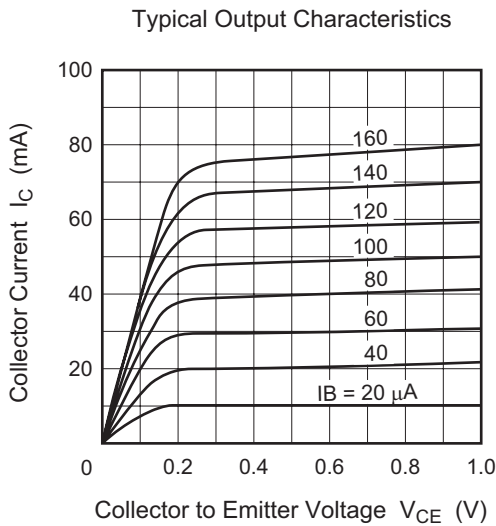
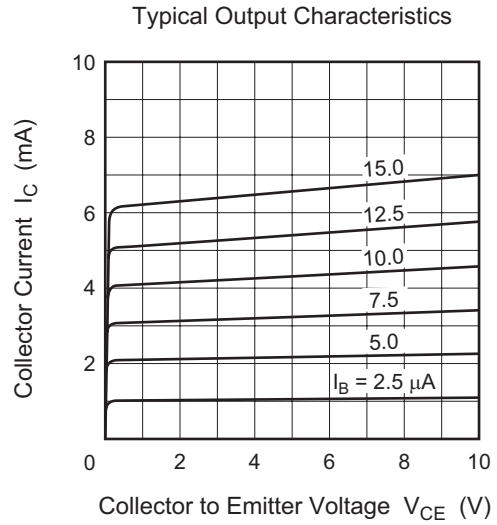
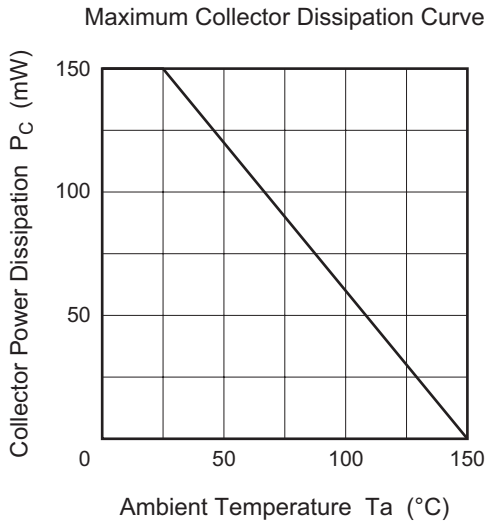
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	30	—	—	V	$I_C = 10 \mu A, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	15	—	—	V	$I_C = 1 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	—	—	V	$I_E = 10 \mu A, I_C = 0$
Collector cutoff current	I_{CBO}	—	—	1.0	μA	$V_{CB} = 20 \text{ V}, I_E = 0$
DC current transfer ratio	h_{FE}^{*1}	250	—	800		$V_{CE} = 1 \text{ V}, I_C = 150 \text{ mA}^{*2}$
Base to emitter voltage	V_{BE}	—	—	1.0	V	$V_{CE} = 1 \text{ V}, I_C = 150 \text{ mA}^{*2}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	—	0.5	V	$I_C = 500 \text{ mA}, I_B = 50 \text{ mA}^{*2}$
Gain bandwidth product	f_T	—	250	—	MHz	$V_{CE} = 1 \text{ V}, I_C = 150 \text{ mA}^{*2}$

Notes: 1. The 2SD1306 is grouped by h_{FE} as follows.

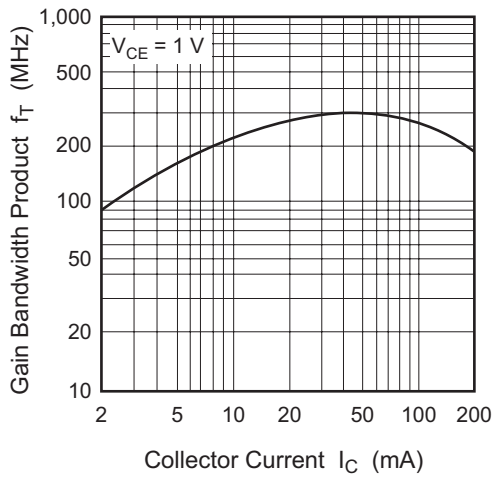
2. Pulse test

Grade	D	E
Mark	ND	NE
h_{FE}	250 to 500	400 to 800

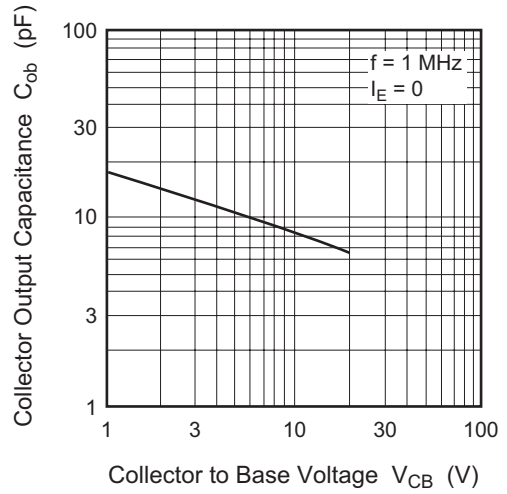
Main Characteristics



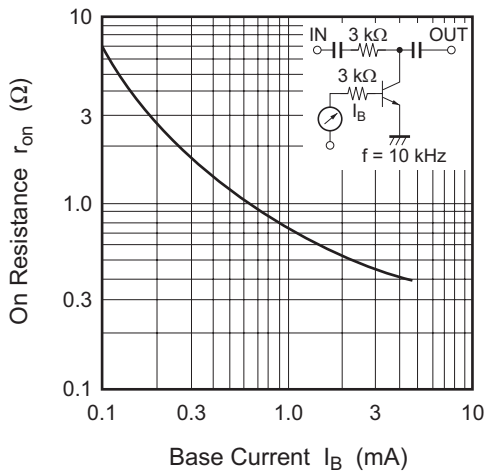
Gain Bandwidth Product vs. Collector Current



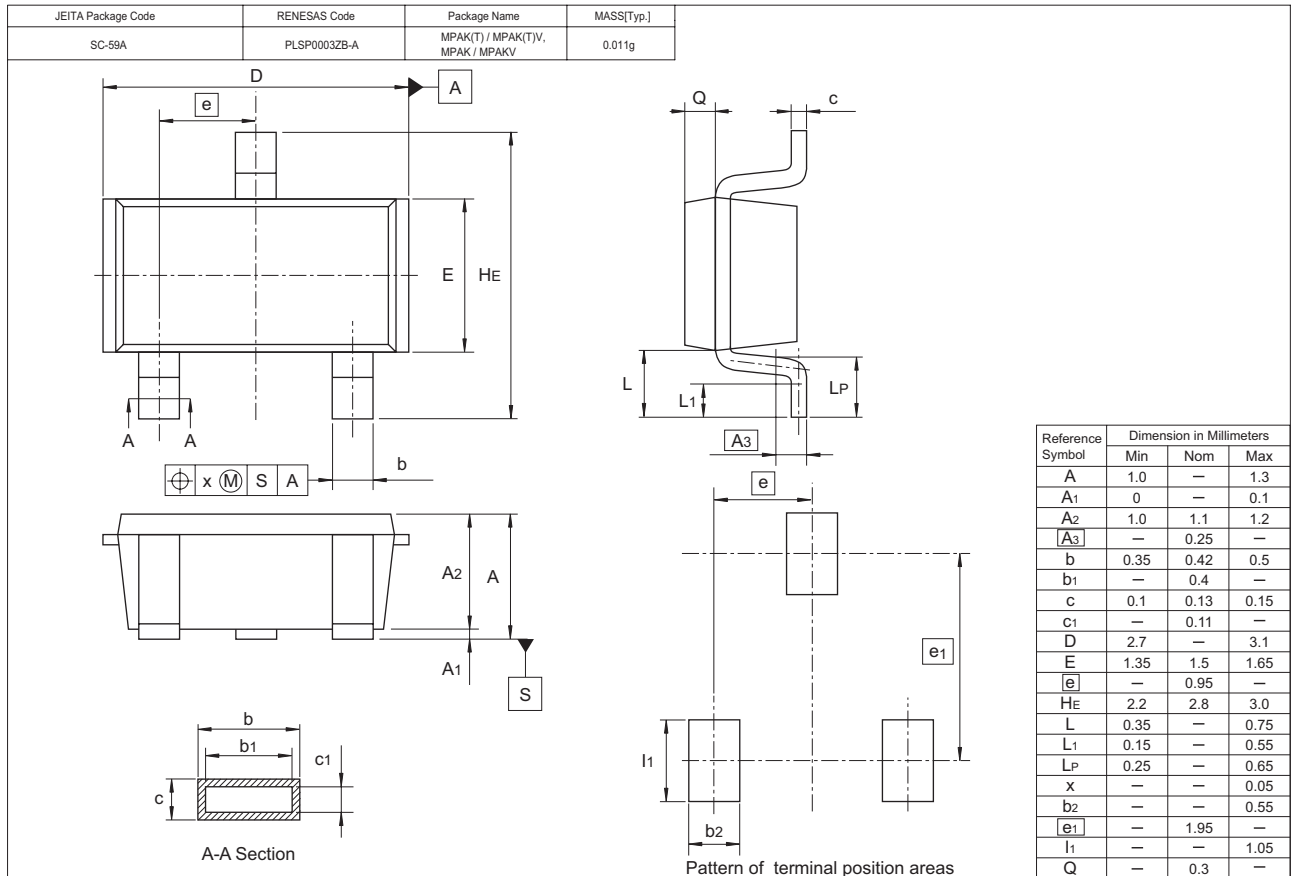
Collector Output Capacitance vs. Collector to Base Voltage



On Resistance vs. Base Current



Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SD1306NDTL-E	3000	φ 178 mm Reel, 8 mm Emboss Taping
2SD1306NETL-E		

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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